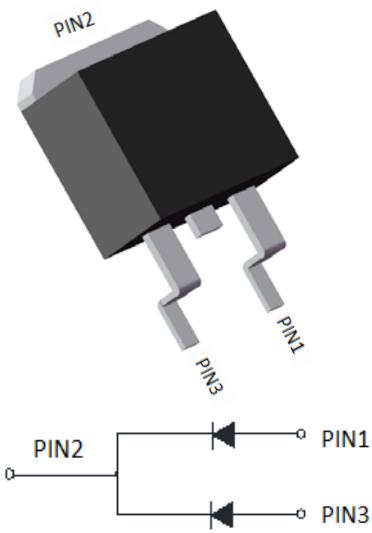




Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Part no. with suffix "Q" means AEC-Q101 qualified

Typical Applications

Typical applications are in switching power supplies, converters, automotive, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRB4060CTQ
Device marking code			MBRB4060CT
Repetitive peak reverse voltage	V_{RRM}	V	60
Average Rectified Output Current @60Hz -sine wave, $T_C=90^\circ\text{C}$	I_o	A	40
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	I_{FSM}	A	300
Current Squared Time @ $1\text{ms} \leq t \leq 8.3\text{ms}$ $T_J=25^\circ\text{C}$	I^2t	A^2s	373
Storage Temperature	T_{stg}	$^\circ\text{C}$	-55 ~ +150
Junction Temperature	T_J	$^\circ\text{C}$	-55 ~ +150

■ Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS		Typ	Max
Instantaneous forward voltage per diode	V_F	V	$I_F=20\text{A}$	$T_J=25^\circ\text{C}$	0.69	0.73
			$I_F=20\text{A}$	$T_J=125^\circ\text{C}$	0.60	0.68
Typical junction capacitance per diode	C_J	pF	$V_R=4\text{V}$, $f=1\text{ MHz}$		790	
Instantaneous reverse current per diode	I_R	mA	$V_R=60\text{V}$	$T_J=25^\circ\text{C}$	-	0.1
				$T_J=125^\circ\text{C}$	-	20

**■Characteristics (Typical)**

Fig.1:Forward Current Derating Curve

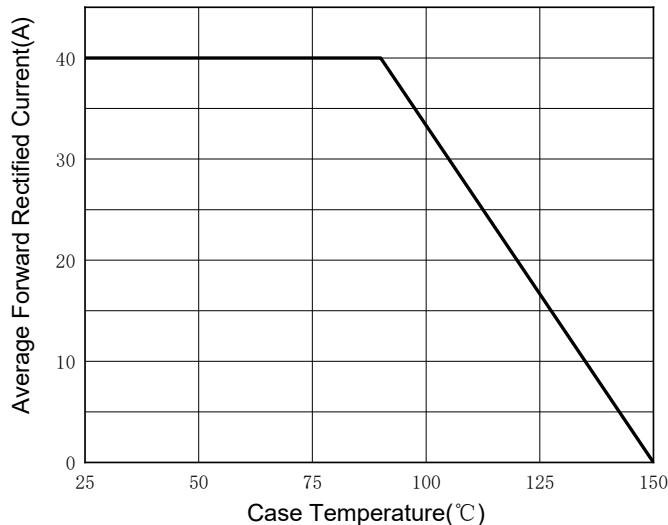


Fig.2: Forward Surge Current Capability(Per Diode)

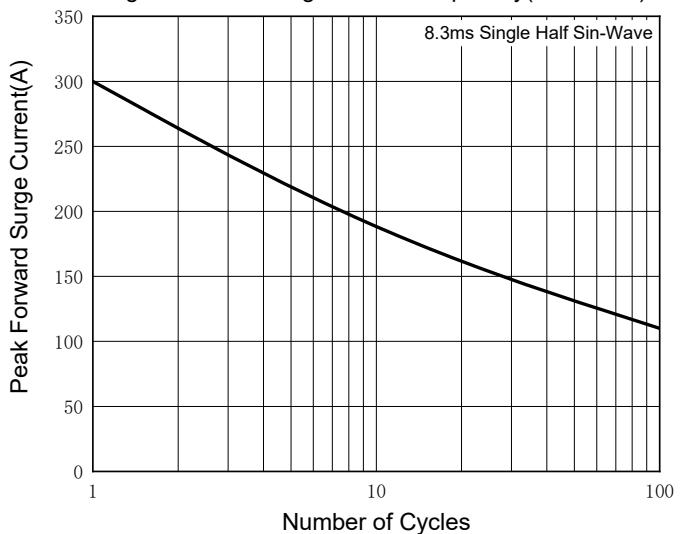


Fig.3:Typical Instantaneous Forward Characteristics(Per Diode)

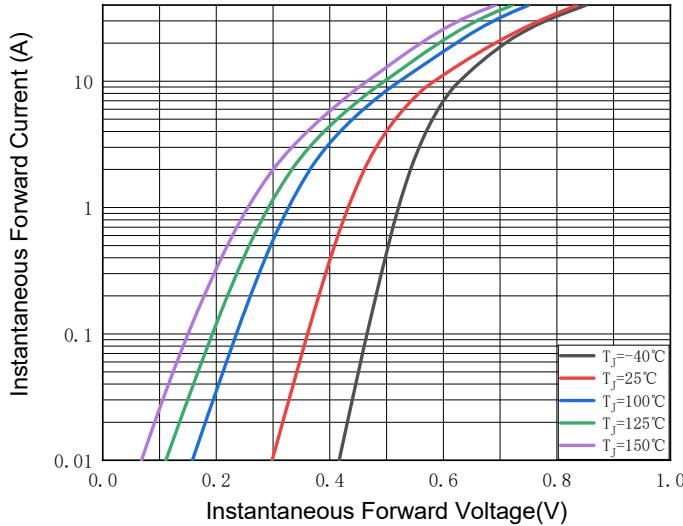


Fig.4:Typical Reverse Leakage Characteristics(Per Diode)

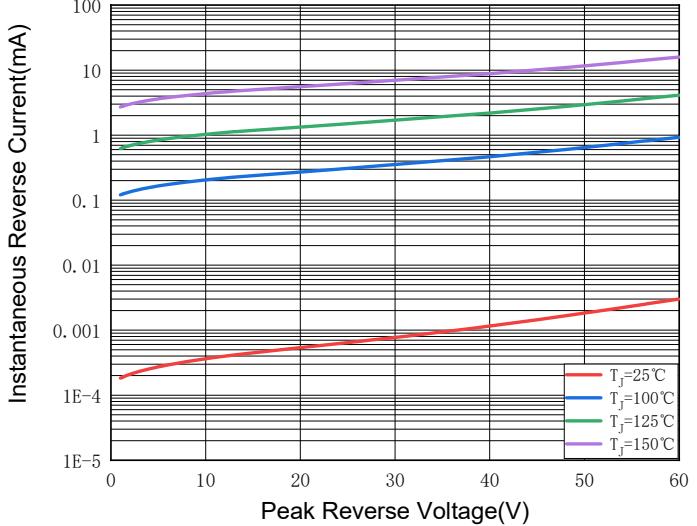
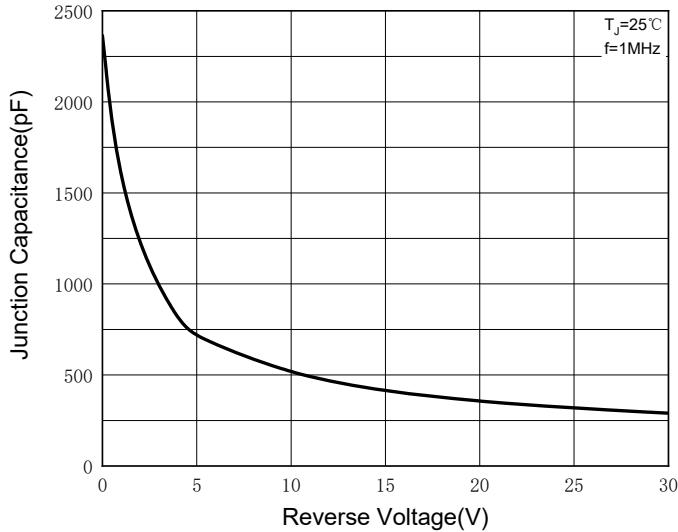


Fig.5:Typical Junction Capacitance(Per Diode)





MBRB4060CTQ

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRB4060CTQ
Typical thermal resistance per diode	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	40 ⁽¹⁾
	$R_{\theta J-C}$	$^\circ\text{C}/\text{W}$	4 ⁽¹⁾

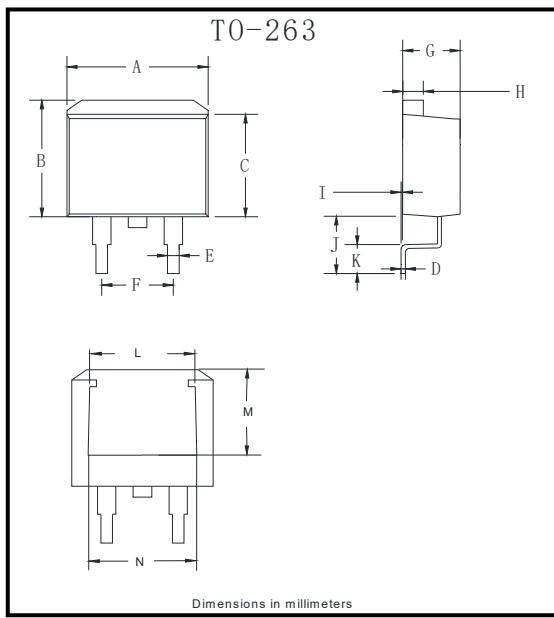
Note:

(1) Thermal resistance from junction to ambient and from junction to case mounted on P.C.B with 25.4mm*25.4mm copper pad areas.

■ Ordering Information (Example)

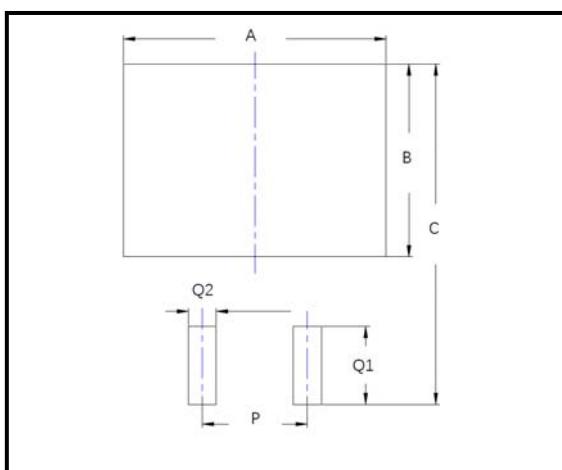
PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRB4060CTQ	Approximate 1.43	1000	2000	10000	Reel

■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	10.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35



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